

December 2014

# FCD620N60ZF

# N-Channel SuperFET<sup>®</sup> II FRFET<sup>®</sup> MOSFET 600 V, 7.3 A, 620 m $\Omega$

## **Features**

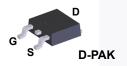
- 650 V @ T<sub>J</sub> = 150°C
- Typ.  $R_{DS(on)}$  = 528 m $\Omega$
- Ultra Low Gate Charge (Typ. Qg = 20 nC)
- Low Effective output Capacitance (Typ. C<sub>oss(eff.)</sub> = 71 pF)
- · 100% Avalanche Tested
- · ESD Improved Capacity
- · RoHS Compliant

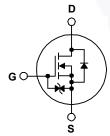
# **Applications**

- · LCD / LED / PDP TV and Monitor Lighting
- · Solar Invertor / AC-DC Power Supply

# Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SuperFET II FRFET® MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





## Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol		Parameter		FCD620N60ZF	Unit
V <sub>DSS</sub>	Drain to Source Voltage			600	V
V	Gate to Source Voltage	- DC		±20	V
V <sub>GSS</sub> G	Gate to Source voltage	- AC	(f > 1 Hz)	±30	7 V
Danier Ourseast		- Continuous (T <sub>C</sub> = 25°C)		7.3	Α
Drain Current	- Continuous (T <sub>C</sub> = 100°C)		4.6	A	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	21.9	Α
E <sub>AS</sub>	Single Pulsed Avalanche Energ	Single Pulsed Avalanche Energy (Note 2)		135	mJ
I <sub>AR</sub>	Avalanche Current		(Note 1)	1.5	Α
E <sub>AR</sub>	Repetitive Avalanche Energy		(Note 1)	0.89	mJ
du/dt	MOSFET dv/dt			100	VIIno
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	50	V/ns
D	Payer Dissipation	(T <sub>C</sub> = 25°C)		89	W
$P_{D}$	Power Dissipation	- Derate Above 25°C		0.71	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temper	Operating and Storage Temperature Range			°C
TL	Maximum Lead Temperature for	r Soldering, 1/8" from Case for 5 Second	S	300	οС

## **Thermal Characteristics**

Symbol	Parameter FCD620N60ZF			
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.4	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	100	- 0/00	

# **Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCD620N60ZF	FCD620N60ZF	DPAK	Tape and Reel	330 mm	16 mm	2500 units

# **Electrical Characteristics** $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Chara	cteristics					
D\/	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	600	-	-	V
BV <sub>DSS</sub> Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 150^{\circ}\text{C}$	650	-	-	\ \ \	
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 10 mA, Referenced to 25°C	-	0.67	-	V/°C
BV <sub>DS</sub>	Drain-Source Avalanche Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 7.3 A	-	700	-	٧
	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 480 V, V <sub>GS</sub> = 0 V	-	-	10	
I <sub>DSS</sub>	Zero Gate voltage Drain Current	$V_{DS} = 480 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	-	20	μΑ
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V	-	-	±10	μΑ

## **On Characteristics**

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	3	-	5	V
R <sub>DS(on)</sub>	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 3.6 \text{ A}$	-	0.528	0.62	Ω

# **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 05.V V 0.V	-	855	1135	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		625	830	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	_   -	-	30	45	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 380 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	16	-	pF
C <sub>oss(eff.)</sub>	Effective Output Capacitance	$V_{DS} = 0 \text{ V to } 480 \text{ V}, V_{GS} = 0 \text{ V}$	-	71	-	pF
Q <sub>g(tot)</sub>	Total Gate Charge at 10V	V <sub>DS</sub> = 380 V, I <sub>D</sub> = 3.6 A,	-	20	36	nC
$Q_{gs}$	Gate to Source Gate Charge	V <sub>GS</sub> = 10 V	-	4.5	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge	(Note 4)	-	7.7	-	nC
ESR	Equivalent Series Resistance	f = 1 MHz	-	2.7	-	Ω

## **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time		-/	15	40	ns
t <sub>r</sub>		$V_{DD} = 380 \text{ V}, I_D = 3.6 \text{ A},$	7-	7	24	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_g = 4.7 \Omega$	/ -	35	80	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4)	-	10	30	ns

## **Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Drain to Source Diode Forward Current		-	-	7.3	Α
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	-	21.9	Α
$V_{SD}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 3.6 A	-	-	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 3.6 A,	-	84	/ -	ns
Q <sub>rr</sub>	Reverse Recovery Charge	$dI_F/dt = 100 A/\mu s$	-	0.325	-	μС

#### Notes:

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2.  $I_{AS}$  = 1.5 A,  $V_{DD}$  = 50 V,  $R_{G}$  = 25  $\Omega$ , starting  $T_{J}$  = 25°C.
- 3. I  $_{SD} \le 3.6$  A, di/dt  $\le 200$  A/ $\mu s, V_{DD} \le BV_{DSS},$  starting T  $_J$  = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

# **Typical Performance Characteristics**

Figure 1. On-Region Characteristics

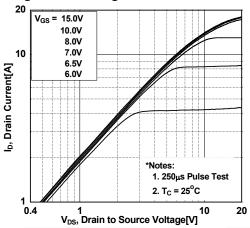


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

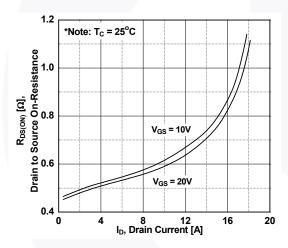


Figure 5. Capacitance Characteristics

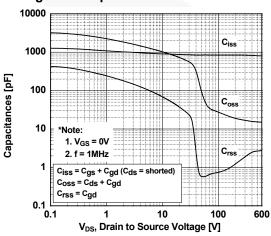


Figure 2. Transfer Characteristics

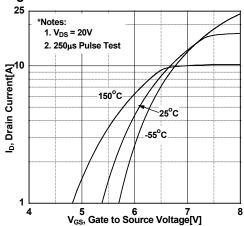


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

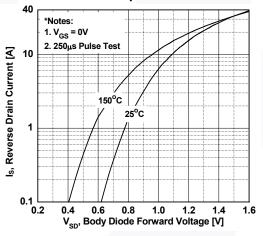
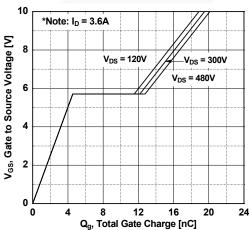


Figure 6. Gate Charge Characteristics



# **Typical Performance Characteristics** (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

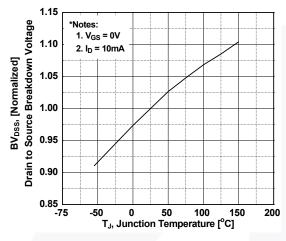


Figure 9. Maximum Safe Operating Area

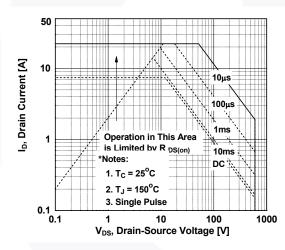


Figure 11. Eoss vs. Drain to Source Voltage

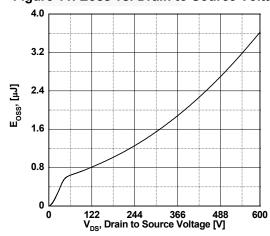


Figure 8. On-Resistance Variation vs. Temperature

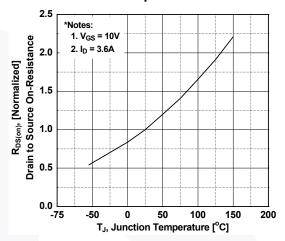
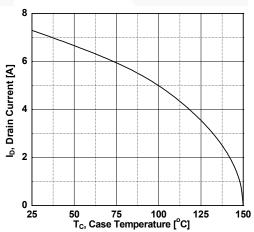
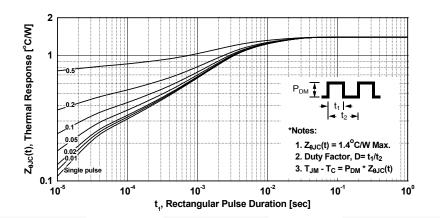


Figure 10. Maximum Drain Current vs. Case Temperature



# **Typical Performance Characteristics** (Continued)

**Figure 12. Transient Thermal Response Curve** 



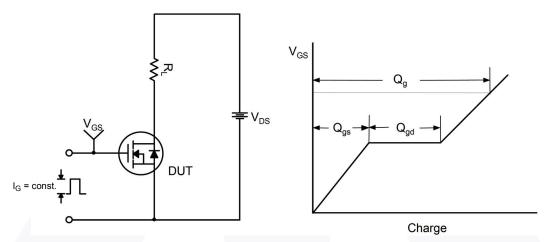


Figure 13. Gate Charge Test Circuit & Waveform

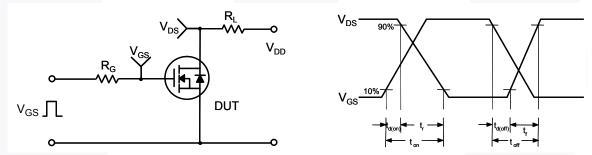


Figure 14. Resistive Switching Test Circuit & Waveforms

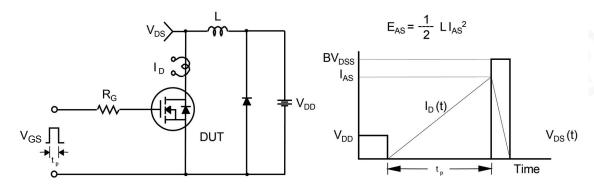


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms

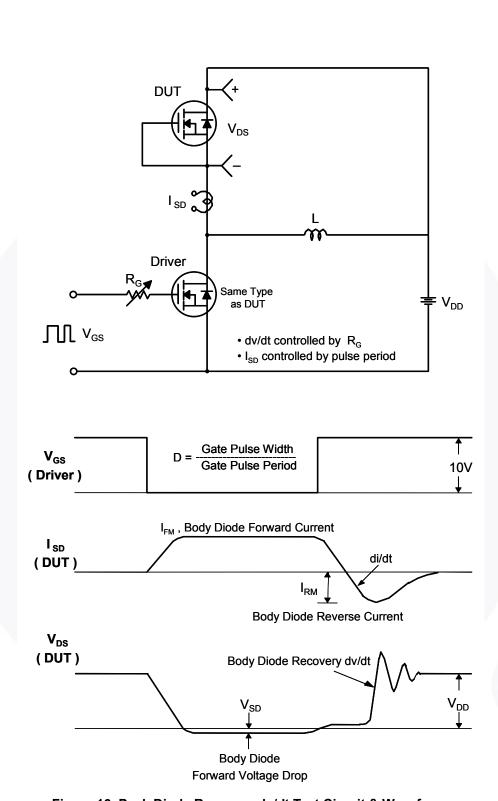


Figure 16. Peak Diode Recovery dv/dt Test Circuit & Waveforms

## **Mechanical Dimensions**

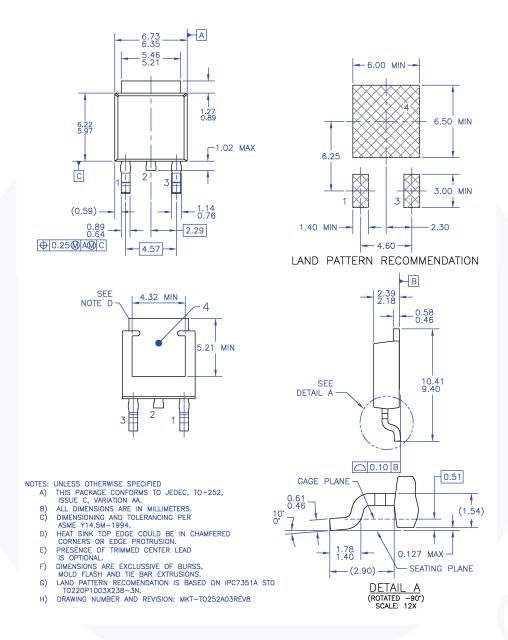


Figure 17. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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